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**\*BIBDATASHEET\***

Bib Data Sheet

CONFIRMATION NO. 2895

SERIAL NUMBER 10/681,280	FILING DATE 10/09/2003  RULE	CLASS 365	GROUP ART UNIT 2824	ATTORNEY DOCKET NO.
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**APPLICANTS**

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**\*\* CONTINUING DATA \*\*\*\*\***

This application is a CON of 10/388,444 03/17/2003 PAT 6,683,811  
which is a CON of 10/095,565 03/13/2002 PAT 6,567,311  
which is a CON of 09/961,300 09/25/2001 PAT 6,385,092  
which is a CON of 09/714,552 11/17/2000 PAT 6,392,932  
which is a CON of 09/468,329 12/21/1999 PAT 6,157,573  
which is a CON of 09/342,231 06/29/1999 PAT 6,023,425  
which is a CON of 09/135,175 08/18/1998 PAT 5,982,668  
which is a CON of 08/889,191 07/08/1997 PAT 5,867,428

*HN(YES)*

**\*\* FOREIGN APPLICATIONS \*\*\*\*\***

JAPAN 8-178965 07/09/1996  
JAPAN 9-126793 05/16/1997

*HN(YES)*

IF REQUIRED, FOREIGN FILING LICENSE GRANTED  
**\*\* 03/09/2004**

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 19	TOTAL CLAIMS 9	INDEPENDENT CLAIMS 2
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35 USC 119 (a-d) conditions met  
☒ yes ☐ no ☐ Met after Allowance

Verified and Acknowledged  
Examiner's Signature: *HIEN NGUYEN* Initials: *HN*

**ADDRESS**  
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**TITLE**  
Nonvolatile memory system, semiconductor memory, and writing method